

Flow Induced Organization and Memory of a Vortex Lattice

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We report on experiments probing the evolution of a vortex state in response to a driving current in 2H-NbSe₂ crystals. By following the vortex motion with fast transport measurements we find that the current enables the system to reorganize and access new configurations. During this process the system exhibits a long-term memory: if the current is turned off the vortices freeze in place remembering their prior motion. When the current is restored the motion resumes where it stopped. The experiments provide evidence for a dynamically driven structural change of the vortex lattice and a corresponding dynamic phase diagram that contains a previously unknown regime where the critical current can be either *increased* or *decreased* by applying an appropriate driving current.

PACS numbers: 74.60.Ge, 74.60.Jg, 74.60.Ec

Vortices in a type II superconductor exhibit remarkably rich and sometimes surprising collective behavior. The underlying physics is a delicate balance between two competing forces: one is the mutual interaction between vortices which promotes order and the other is pinning, caused by randomly distributed material defects, which favors disorder [1–3]. A striking example of this competition is the "peak effect" - a sudden increase in the critical current just below the superconducting transition temperature, T_c , attributed to a violent structural reorganization when pinning overcomes the ordering influence of interactions [3–6]. Another outcome of this balance is that the vortices are subject to an energy landscape with many metastable states leading to history dependence and nonlinear behavior [4–14]. For example a vortex array prepared by field cooling, where the magnetic field is applied before cooling through T_c , becomes trapped in a metastable state that has a higher critical current and is more disordered than one prepared by zero field cooling - where the field is applied after cooling [4,5]. Setting the vortices in motion with an external current releases them to explore the energy landscape and to access new states [7–9], but thus far the dynamics of this process was inaccessible to experiments.

To probe the vortex dynamics we have devised a technique that uses fast current ramps and pulses to track the evolution of a vortex lattice as it unpins and starts moving. We find that when the vortices are set in motion they organize into a new state whose properties are determined by the driving current. The experiments lead to a dynamic phase diagram containing four regimes as a function of increasing current: A) pinned vortex array at the lowest currents; B) at higher currents a region of motional reorganization and repinning where the vortices settle into a state whose critical current is equal to the driving current; C) at still higher currents channels of ordered moving vortices cut through domains of disordered stationary ones; D) at the highest currents all the vortices unpin and form an ordered state with low critical

current.

The vortex motion is detected by measuring the longitudinal voltage across the sample $V = vBl$, where v is the vortex velocity, B the magnetic field and l the distance between the voltage contacts. As long as the vortex array is pinned the current flow is dissipationless and only when a critical current I_c is exceeded, unpinning it, will a voltage appear. It was first shown by Larkin and Ovchinnikov [3] that for weak pinning superconductors I_c is a measure of the degree of order in the vortex system. In this case, as was confirmed by recent SANS [15] and transport measurements [5], the critical current density is inversely proportional to the size of an ordered vortex domain and I_c can be used, as was done here, to quantify the degree of vortex order.

The data were acquired on a Fe (200ppm) doped single crystal of 2H-NbSe₂ of size of $(3 \times 1 \times 0.015)$ mm³ and $T_c = 5.95$ K. Our measurements employed a standard four probe technique with low resistance contacts made with Ag_{0.1}In_{0.9} solder. The current ramps and pulses were generated with a Wavetek 164 and the voltage response was measured with a fast (INA103) amplifier. The magnetic field was kept along the c axis of the sample and the current in the a - b plane. All the data were taken after the sample is zero field cooled (ZFC). Previous experiments on similar samples revealed novel types of nonlinear behavior including frequency memory and long glassy relaxation times that were observed in the lower part of the peak effect region [16]. In the present experiments we find that this is also the region where the value of the critical current changes during the measurement.

Fig.1 shows the response to two types of current ramps, fast (FCR -ramping rate of 200A/s), and slow current ramps (SCR -ramping rate of 1mA/s). The critical current was defined as the current at which the voltage reaches 1μ V. The inset in Fig.1, which shows the current-voltage ($I - V$) characteristics for both ramps, illustrates that the response depends on the speed of measurement. In particular the critical current I_{cf} , obtained with the

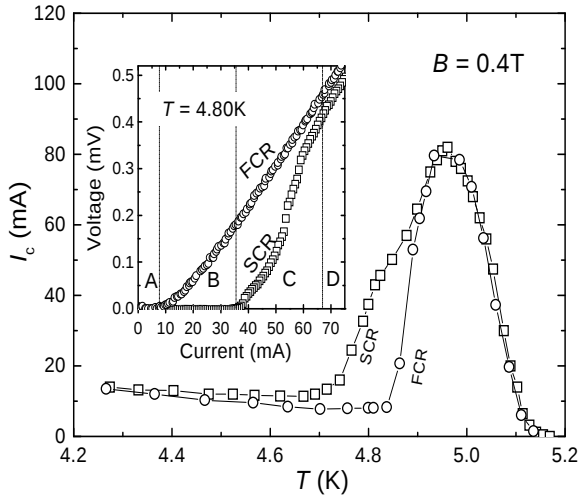


FIG. 1. Temperature dependence of I_c detected by slow (SCR) and fast (FCR) current ramps. Inset: $I - V$ curves in response to SCR (1mA/s) and FCR (200A/s). The labels A,B,C,D illustrate the four regions of the dynamic phase diagram.

FCR, is lower than I_{cs} , the value obtained for the SCR. The temperature dependence of I_{cs} and I_{cf} is shown in the main panel of Fig.1. A strong peak effect as reported in Ref.[5] is seen in both data sets. The fact that $I_{cf} \leq I_{cs}$, for all data points means that the ZFC state probed by the FCR is always more ordered than the SCR state, leading to the conclusion that during the SCR the vortex array has time to reorganize into a more strongly pinned state. This organization does not however produce a voltage signal in the SCR measurements because it decays too fast to be resolved.

To observe the reorganization directly we carried out fast measurements with $2\mu\text{sec}$ temporal resolution, which enabled us to follow the decay of the voltage response to a current step $I > I_{cf}$ as shown in Fig.2. We note that upon applying the current step the vortex response is instantaneous as expected of essentially massless objects [17] when they respond elastically. As time progresses the voltage decreases despite the fact that the driving current is kept constant. After a sufficiently long waiting time the voltage decays to zero for driving currents in the range $I_{cf} < I < I_{cs}$. The decay is also observed for driving currents in excess of I_{cs} indicating that the moving vortex array organizes itself into less ordered state even though it is not coming to a full stop. In either case the organization proceeds in two steps. On long time scales there is a clear decay which exhibits a stretched exponential time dependence $\exp(-t/\tau)^\alpha$ where both the characteristic time scale, τ and the exponent α depend on current and temperature. This type of relaxation is typical of the dynamics observed in glasses. By contrast, on

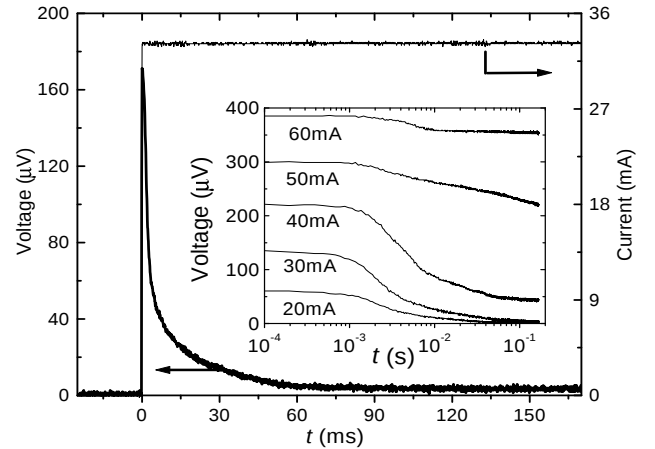


FIG. 2. Time dependence of response to a current step. The inset shows the response to steps of different amplitudes.

short time scales the response is almost constant showing no measurable decay. This is consistent with the observation of Ref. [8] that the vortex pattern does not change instantaneously. It is this delay before the decay sets in that makes it possible to observe the pristine vortex state - before it has time to reorder - by using a fast current ramp technique.

During the reorganization a striking long-term memory is observed. A typical result is shown in Fig.3(a) where we plot the response to a current pulse of amplitude I . When the current is interrupted during the decay, the voltage drops to zero instantaneously. Subsequently, when the current is restored after a waiting time with zero current, the voltage decay resumes where it stopped the moment the current was turned off. The waiting times for which the lattice remembers its state of motion prior to being stopped can be very long (we checked waiting times of up to 20 hours) provided the field and temperature remain unchanged. Other effects associated with quenching of the vortex motion where observed in experiments on the structure [7,18,19] and transport properties [20].

Long-term memory occurs in systems that can be trapped indefinitely in a metastable state. In the case of a vortex array this implies that the energy scale of the pinning potential is much larger than that of thermal fluctuations. The current lowers the barriers of the pinning potential and sets the vortices in motion allowing them to explore new states and eventually settle into a more strongly pinned state. It is thus the applied current rather than the temperature that drives the system towards equilibrium. How robust are these metastable states or equivalently how large can the current be before the vortices become untrapped? To explore the interplay between current and pinning we carried out the experiment shown in Fig.3(b). The ZFC vortex lattice is driven with a current pulse of amplitude I for 1.6msec during

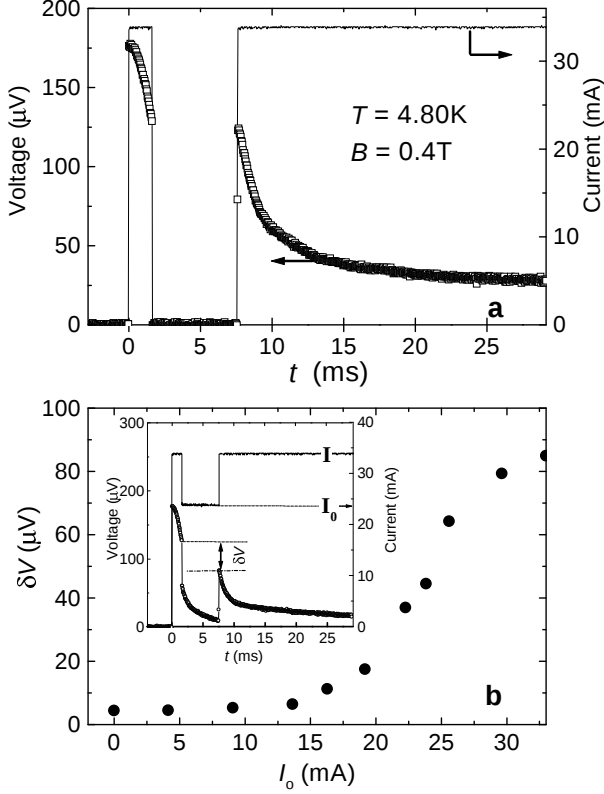


FIG. 3. Memory of a vortex array. (a) During the decay the current is removed and later it is restored to its initial value. The lines and the open circles are the current and the response respectively. (b) δV as a function of I_0 . The definitions of δV and I_0 are shown in inset.

which the response decays correspondingly. The current is then suddenly reduced to a lower value I_0 for 6ms during which the voltage decays at a different rate, and subsequently it is restored to its original value. Plotting δV , the voltage decay during the reduced current pulse, as a function of I_0 , we find that there is indeed a finite value of I_0 below which the system does not evolve with time and retains its memory. This value of the current coincides with the critical current of the vortex lattice at the moment at which the reduced current is applied.

The memory can be a powerful tool in the study of vortex dynamics. Most probes of the vortex structure require long times to produce one data point or a picture, typically 45 seconds in scanning Hall probe microscopy [21] and 15 minutes in SANS [7]. It would be impossible to observe the motional reorganization with these techniques. But as our experiments have shown, the vortex structure can be frozen at any moment during its motion by removing the driving current. The quenched vortex system maintains its structure and can then be probed directly. We used this method here to observe the vortex

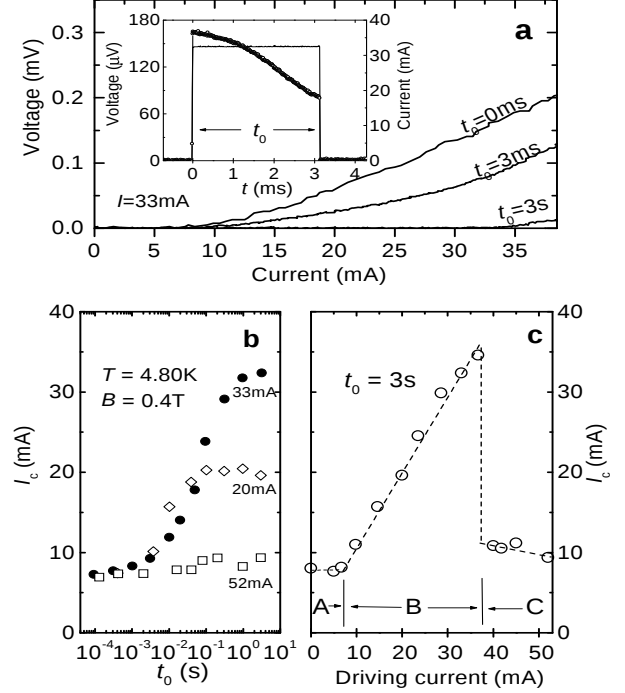


FIG. 4. (a) $I - V$ curves obtained with a fast current ramp following decay periods $t_0 = 0, 3\text{ms}$ and 3s with current $I = 33\text{mA}$. The definition of t_0 is shown in the inset. (b) Evolution of critical current with time in the presence of driving currents $I = 20, 33$, and 52mA . (c) Data for I_c obtained at $t_0 = 3\text{s}$ and various driving currents. The symbols A, B, C represent the three regimes of the dynamic phase diagram. The dashed line is a guide to the eye.

reorganization by quenching the system at various times during its motion and measuring its critical current with the FCR method.

As an example, we show in Fig.4(a) the response to an FCR at decay times $t_0 = 0, 3\text{ms}$ and 3s . Clearly, I_c increases with increasing decay time. In Fig.4(b) we show the dependence of I_c on decay time for driving currents $I = 20, 33$ and 52mA . For current amplitudes $I_{cf} < I \leq I_{cs}$, the critical current increases with decay time and saturates at a value which is approximately equal to the driving current. In Fig.4(c) we show the dependence of I_c on I following a long decay time of $t_0 = 3\text{s}$. As long as $I_{cf} < I \leq I_{cs}$ we find that $I_c \sim I$, in other words the system can be prepared with any desired critical current in this range simply by priming it with the appropriate driving current. For $I > I_{cs}$, there is an abrupt drop in I_c to a value only slightly above that in the ordered state. We interpret this drop in terms of the formation of a channel of unpinning and motionally ordered vortices. The fact that critical current is slightly higher than that of the ZFC state may indicate that, as predicted by theory [10,11], the motionally ordered state resembles a smectic rather than a crystal.

We now show that for $I > I_{cs}$ our data is consistent with channel formation and estimate the number of vortices in channels. First we interpret the information contained in the $I - V$ curves in terms of vortex motion: I_c gives the force required to set the vortices in motion and the cordal resistance, defined as $R_c = V/(I - I_c)$, measures the number of moving vortices in response to a current I . When all the vortices are moving R_c takes the maximum value, given by the Bardeen-Stephen resistance [22] $R_{BS} = R_n(\Phi_0/H_{c2})n$, where R_n is the normal state resistance, Φ_0 the fundamental unit of flux, H_{c2} the upper critical field and n is the vortex density. If only a fraction of the vortices move, R_c is reduced proportionately. We note that for the FCR data in the inset of Fig.1 the cordal resistance is close to the maximum value, $R_c^f = 8.75\text{m}\Omega = 0.94R_{BS}$ which means that essentially all the vortices move. By contrast the $I - V$ curve obtained with the SCR for the same initial vortex state is different: it has a much higher critical current and once the vortex motion is detectable the slope increases with current. In this case the number of moving vortices depends on the current and can be estimated by using the result of Fig.4(c) that for $I > I_{cs}$, the moving vortex array is in a state with critical current $\sim I_{cf}$. Therefore, the ratio of voltage response obtained with the SCR to that obtained with the FCR $V_s(I)/V_f(I) = R_c^s/R_c^f$ is equal to the ratio of moving vortices in the two measurements. Since in the FCR case the entire array is moving $V_s(I)/V_f(I)$ is in fact a direct measure the fraction of moving vortices. This result leads to the conclusion that for $I_{cs} < I < 2I_{cs}$ not all the vortices are participating in the motion and those that do move form channels in which the vortices are ordered (because the critical current is close to I_{cf}), consistent with our assumption. The fraction of moving vortices in the SCR increases gradually from zero at $I = I_{cs}$ to 1 when the channels have engulfed the entire sample forming an ordered state.

Based on these results we identify four regions in the dynamic phase diagram as illustrated in Fig.1. In region A where $I < I_{cf}$, the vortex lattice stays pinned and ordered. Region B, where $I_{cf} < I < I_{cs}$, is the regime of motional reorganization and repinning. Here the response decays with time as parts of the lattice break loose settling into stronger pinned configurations until the motion comes to a halt when the vortices reach a state with I_c equal to the driving current. This state contains at least one contiguous region of disordered vortices that provides a low resistance current path along the sample. Region C, where $I_{cs} < I < 2I_{cs}$, is the plastic flow regime in which channels of moving ordered vortices cutting across the sample are embedded in domains of disordered stationary vortices. In region D, $I > 2I_{cs}$, the entire vortex array unpins and becomes motionally ordered.

We conclude that the current assists the system in choosing a configuration in the energy landscape formed

by the competition between interactions and pinning. The current assisted rearrangement can also account for the fact that the ZFC vortex state has the lowest critical current: as the field is ramped up in the superconducting state, it is initially expelled from the interior of the sample by the screening currents. The vortices can penetrate only when the screening current density exceeds the critical value, and therefore the configuration with the lowest critical current- the ordered state [23] -will be the first to penetrate the sample. For the experiments discussed here the typical ordered domain in the ZFC state contains $\sim 10^3$ vortices. Once the vortices are inside the sample an externally applied current assists them in finding a lower energy configuration by adapting to the pinning potential and becoming more disordered. With increasing current, as the pinning barriers are effectively lowered, larger portions of the pinscape can be explored resulting in progressively more strongly pinned states. Until at $I > I_{cs}$ a channel forms across the sample in which no barriers are encountered allowing free passage of moving, ordered vortices. The motional reorganization does not occur immediately after the array is set in motion but after a delay during which it maintains its prior configuration. This initial hesitation together with the long term memory makes it possible to directly probe these processes with transport measurements and in principle with other techniques as well.

We thank N. Andrei, R. Chitra, W. Henderson, Y. Paltiel, A. Rosch, R. Ruckenstein, S. Bhattacharya and E. Zeldov for useful discussion. The work at Rutgers was supported by NSF-DMR and by DOE.

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